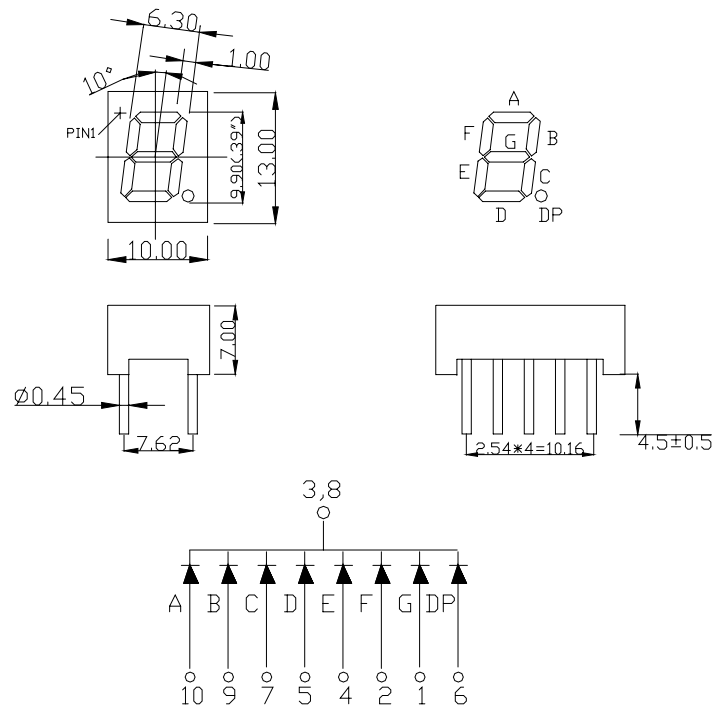


KW1-391C2B

DATA SHEET

Package Dimensions:



Part NO.	Chip Material	Source Color
KW1-391C2B	GaP	Green

Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ± 0.25 mm (.010") unless otherwise noted.
3. Specifications are subject to change without notice.

Absolute Maximum Ratings at Ta=25°C

Parameter	MAX.	Unit
Power Dissipation	100	mW
Peak Forward Current (1/10 Duty Cycle, 0.1ms Pulse Width)	100	mA
Continuous Forward Current	50	mA
Derating Linear From 50°C	0.4	mA/°C
Reverse Voltage	5	V
Operating Temperature Range	-40°C to +80°C	
Storage Temperature Range	-40°C to +80°C	
Lead Soldering Temperature [1.6mm(.063") From Body]	260°C for 5 Seconds	

Electrical Optical Characteristics at Ta=25°C

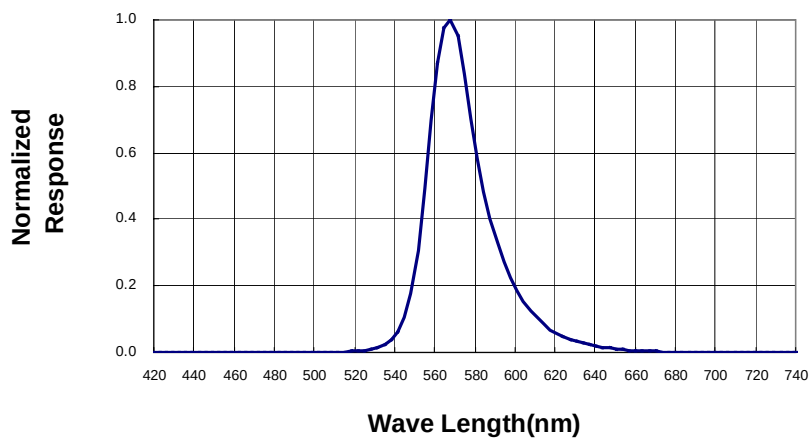
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Luminous Intensity	I_v	7	15	25	mcd	$I_f=20\text{mA}$ (Note 1)
Peak Emission Wavelength	λ_p	563	568	573	nm	$I_f=20\text{mA}$
Spectral Line Half-Width	$\Delta\lambda$	25	30	35	nm	$I_f=20\text{mA}$
Forward Voltage	V_f	1.7	2.2	2.6	V	$I_f=20\text{mA}$
Reverse Current	I_R	---	--	100	μA	$V_R=5\text{V}$

Notes:

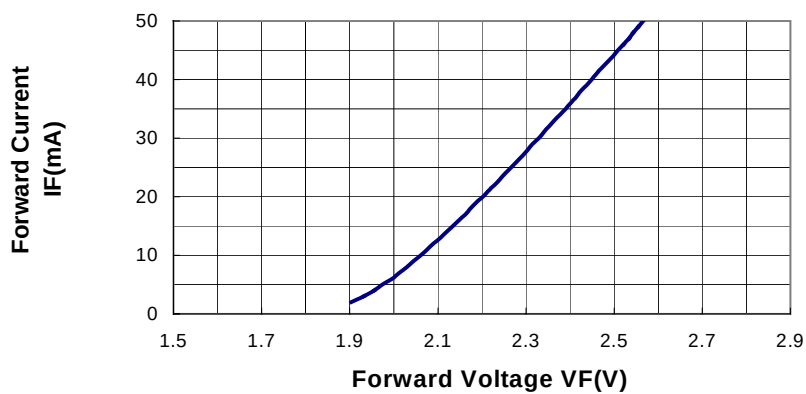
1. Luminous intensity is measured with a light sensor and filter combination that approximates the CIE eye-response curve.

Typical Electrical / Optical Characteristics Curves
(25°C Ambient Temperature Unless Otherwise Noted)

Spectral Radiance (Peak @ 568nm)



**Forward Current
vs Forward Voltage**



**Relative Luminous Intensity
vs Forward Current**

